

3.3 V ESD Protection Diodes

Micro-packaged Diodes for ESD Protection

The ESD1131 is designed to protect voltage sensitive components from ESD. Excellent clamping capability, low leakage, and fast response time provide best in class protection on designs that are exposed to ESD. Because of its small size, it is suited for use in smartphone, smart-watch, or many other portable / wearable applications where board space comes at a premium.

Features

- Low Capacitance (4 pF, I/O to GND)
- Small Body Outline Dimensions
 - ♦ 01005 Size: 0.445 x 0.240 mm
- Protection for the Following IEC Standards:
IEC 61000-4-2 (Level 4)
- Low ESD Clamping Voltage
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS ($T_J = 25^{\circ}\text{C}$ unless otherwise noted)

Rating	Symbol	Value	Unit
Operating Junction Temperature Range	T_J	-55 to +125	$^{\circ}\text{C}$
Storage Temperature Range	T_{stg}	-55 to +150	$^{\circ}\text{C}$
Lead Solder Temperature – Maximum (10 Seconds)	T_L	260	$^{\circ}\text{C}$
IEC 61000-4-2 Contact (ESD)	ESD	± 16	kV
IEC 61000-4-2 Air (ESD)	ESD	± 16	kV

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

See Application Note AND8308/D for further description of survivability specs.



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MARKING DIAGRAM

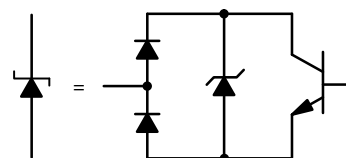
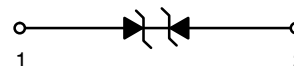


X4DFN2
CASE 718AA



A = Specific Device Code

PIN CONFIGURATION AND SCHEMATIC



ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

ESDM1131

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise specified)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Reverse Working Voltage	V _{RWM}	I/O Pin to GND			3.3	V
Breakdown Voltage	V _{BR}	I _T = 1 mA, I/O Pin to GND	4.0	5.0	6.0	V
Reverse Leakage Current	I _R	V _{RWM} = 3.3 V, I/O Pin to GND			0.1	μA
Clamping Voltage	V _C	I _{PP} = 4 A, (8x20 μs pulse)		5.6		V
Clamping Voltage TLP (Note 1)	V _C	I _{PP} = 8 A } IEC 61000-4-2 Level 2 equivalent (±4 kV Contact, ±4 kV Air)		5.5		V
		I _{PP} = 16 A } IEC 61000-4-2 Level 2 equivalent (±8 kV Contact, ±15 kV Air)		7.0		
Junction Capacitance	C _J	V _R = 0 V, f = 1 MHz		4.0		pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1. ANSI/ESD STM5.5.1 – Electrostatic Discharge Sensitivity Testing using Transmission Line Pulse (TLP) Model.

TLP conditions: Z₀ = 50 Ω, t_p = 100 ns, t_r = 4 ns, averaging window; t₁ = 30 ns to t₂ = 60 ns.

ORDERING INFORMATION

Device	Package	Shipping [†]
ESDM1131MX4T5G	X4DFN2 (Pb-Free)	10,000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

TYPICAL CHARACTERISTICS

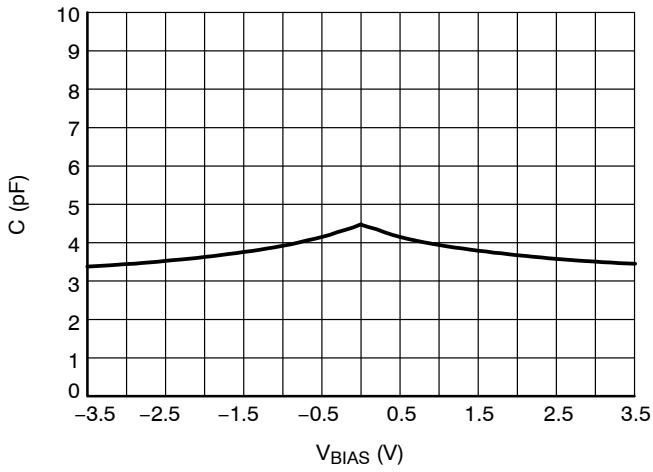


Figure 1. CV Characteristics

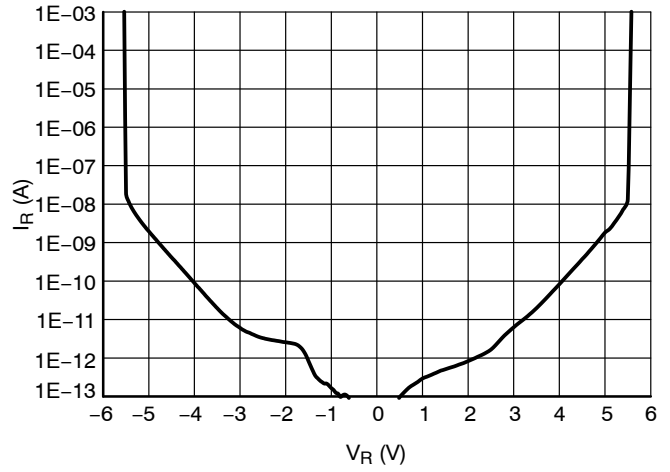


Figure 2. Reverse Leakage Current

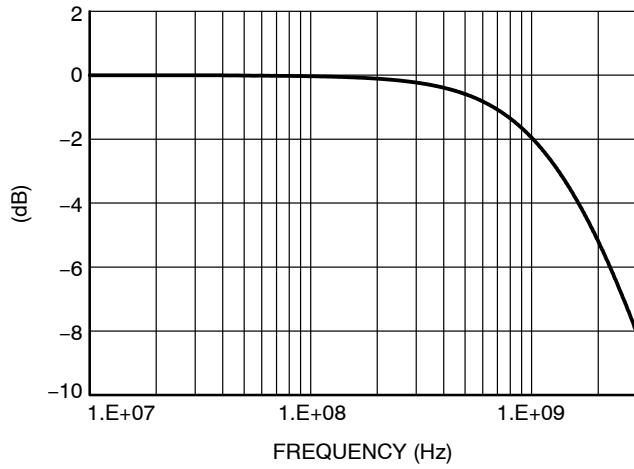


Figure 3. S21 Insertion Loss

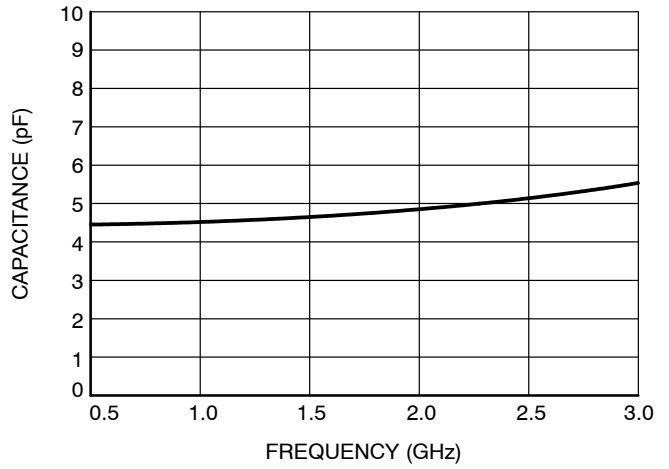


Figure 4. Capacitance over Frequency

TYPICAL CHARACTERISTICS

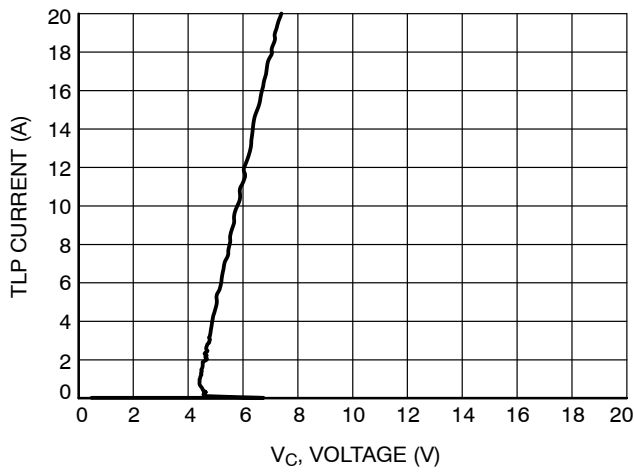


Figure 5. Positive TLP I-V Curve

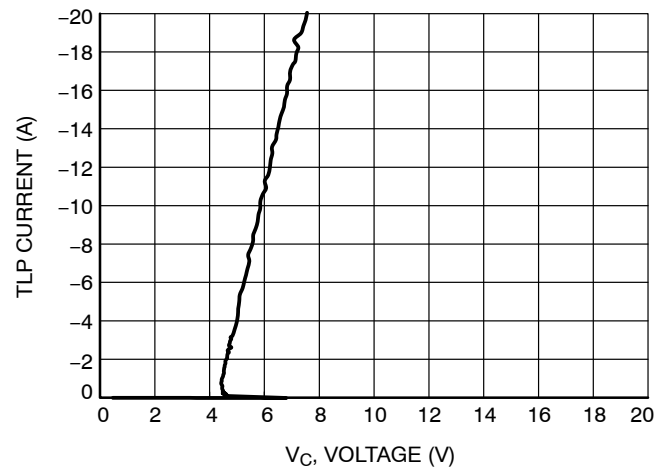


Figure 6. Negative TLP I-V Curve

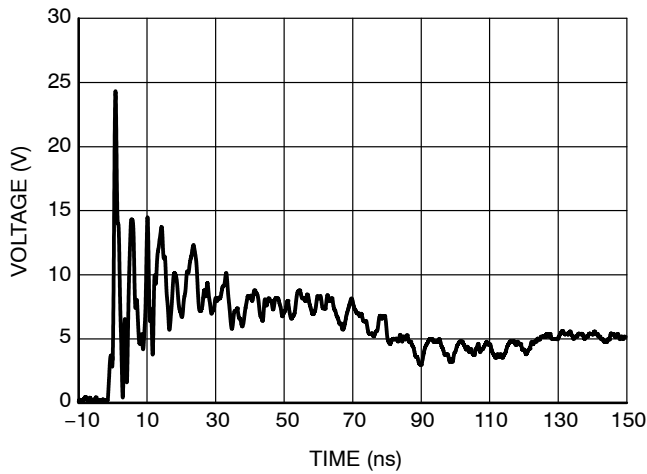


Figure 7. Positive 8 kV ESD Contact Discharge

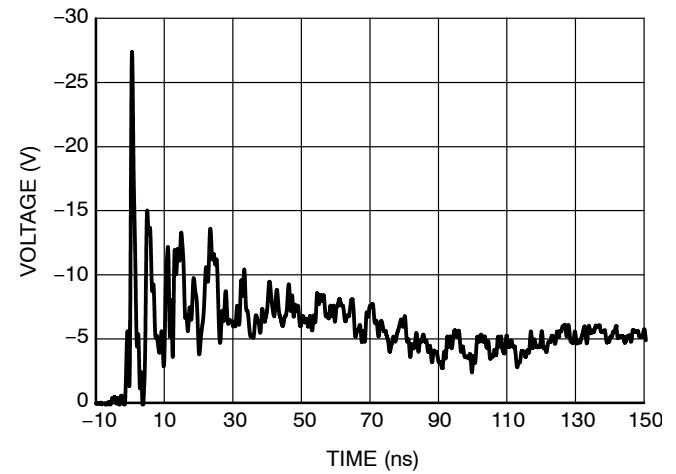


Figure 8. Negative 8 kV ESD Contact Discharge

IEC 61000-4-2 Spec.

Level	Test Voltage (kV)	First Peak Current (A)	Current at 30 ns (A)	Current at 60 ns (A)
1	2	7.5	4	2
2	4	15	8	4
3	6	22.5	12	6
4	8	30	16	8

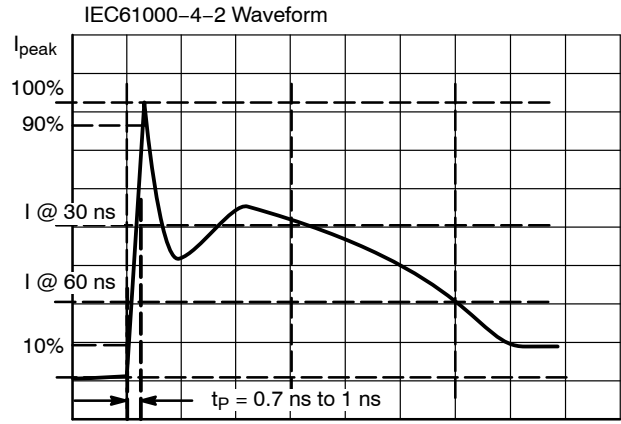


Figure 9. IEC61000-4-2 Spec

Transmission Line Pulse (TLP) Measurement

Transmission Line Pulse (TLP) provides current versus voltage (I-V) curves in which each data point is obtained from a 100 ns long rectangular pulse from a charged transmission line. A simplified schematic of a typical TLP system is shown in Figure 10. TLP I-V curves of ESD protection devices accurately demonstrate the product's ESD capability because the 10s of amps current levels and under 100 ns time scale match those of an ESD event. This is illustrated in Figure 11 where an 8 kV IEC 61000-4-2 current waveform is compared with TLP current pulses at 8 A and 16 A. A TLP I-V curve shows the voltage at which the device turns on as well as how well the device clamps voltage over a range of current levels.

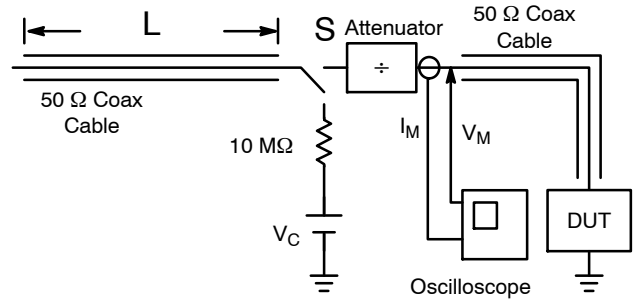


Figure 10. Simplified Schematic of a Typical TLP System

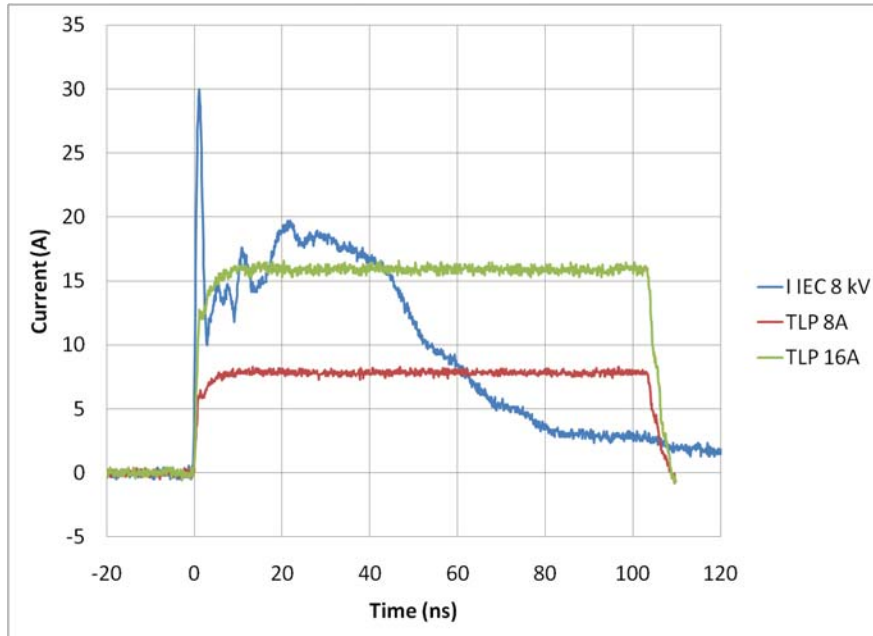
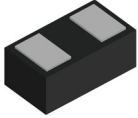
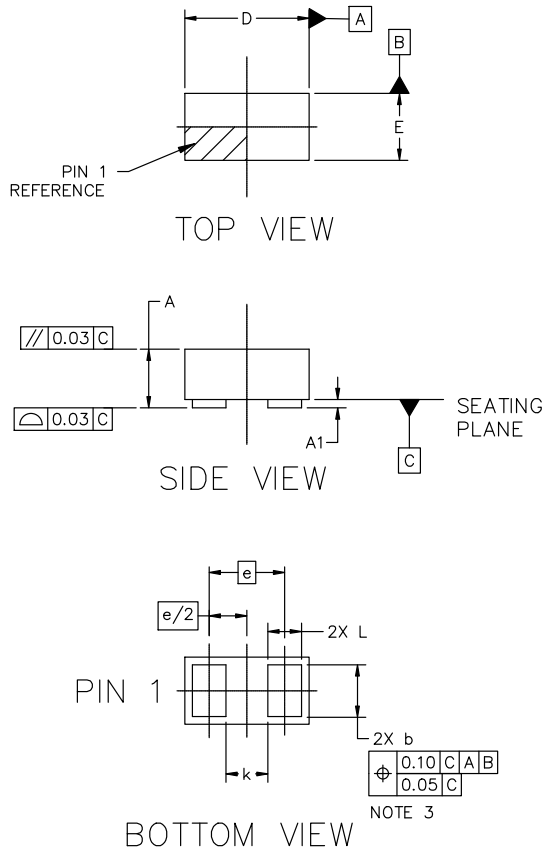


Figure 11. Comparison Between 8 kV IEC 61000-4-2 and 8 A and 16 A TLP Waveforms



X4DFN2, 0.44x0.24x0.18, 0.27P
CASE 718AA
ISSUE B

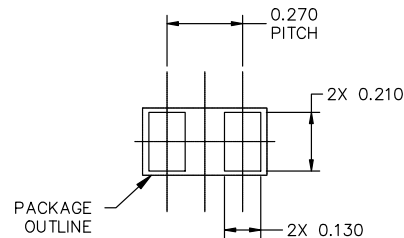
DATE 05 MAR 2025



NOTES:

1. DIMENSIONING AND TOLERANCING AS PER ASME Y14.5M, 2018.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. EXPOSED COPPER ALLOWED AS SHOWN.

MILLIMETERS			
DIM	MIN	NOM	MAX
A	0.150	0.180	0.210
A1	---	---	0.030
b	0.170	0.185	0.200
D	0.415	0.445	0.475
E	0.210	0.240	0.270
e	0.270 BSC		
k	0.125	---	---
L	0.105	0.120	0.135



RECOMMENDED MOUNTING FOOTPRINT

- * For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC MARKING DIAGRAMS*



X = Specific Device Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

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DESCRIPTION:	X4DFN2, 0.44x0.24x0.18, 0.27P	PAGE 1 OF 1

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